

TinyLogic UHS 2-Input NAND Gate, Open Drain Output NC7SZ38

Description

The NC7SZ38 is a single 2–Input NAND gate with open drain output stage from **onsemi**'s Ultra–High Speed Series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra–high speed with high output drive while maintaining low static power dissipation over a very broad V_{CC} operating range. The device is specified to operate over the 1.65 V to 5.5 V V_{CC} range. The inputs and output are high impedance when V_{CC} is 0 V. Inputs tolerate voltages up to 5.5 V, independent of V_{CC} when in the high impedance state. The open drain output stage tolerates voltages up to 6 V independent of V_{CC} when in the high impedance state.

Features

- Ultra-High Speed: $t_{PD} = 2.2 \text{ ns}$ (Typical) into 50 pF at 5 V V_{CC}
- Open Drain Output Stage for OR Tied Applications
- High Output Sink Drive: ±24 mA at 3 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- $\bullet\,$ Matches Performance of LCX Operated at 3.3 V V_{CC}
- Power Down High-Impedance Inputs / Outputs
- Over-Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry
- Ultra−Small MicroPak™ Packages
- Space–Saving SOT23–5, SC–74A and SC–88A Packages
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

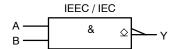
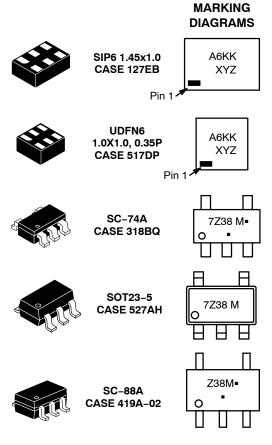


Figure 1. Logic Symbol



A6, 7Z38, Z38 = Specific Device Code

KK = 2-Digit Lot Run Traceability Code XY = 2-Digit Date Code Format

Z = Assembly Plant Code

M = Data Code* ■ Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

Pin Configurations

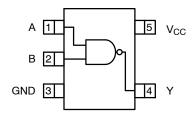


Figure 2. SOT23-5, SC-88A and SC-74A (Top View)

6 V_{CC} B 2 5 NC GND 3 4 Y

Figure 3. MicroPak (Top Through View)

PIN DEFINITIONS

| Pin # SC-88A / SC-74A/ | | | |
|---------------------------|----------------|-----------------|----------------|
| SOT23-5 | Pin # MicroPak | Name | Description |
| 1 | 1 | Α | Input |
| 2 | 2 | В | Input |
| 3 | 3 | GND | Ground |
| 4 | 4 | Υ | Output |
| 5 | 6 | V _{CC} | Supply Voltage |
| | 5 | NC | No Connect |

FUNCTION TABLE

| Inp | Output | |
|-----|--------|----|
| Α | В | Υ |
| L | L | *H |
| L | Н | *H |
| Н | L | *H |
| Н | Н | L |

H = HIGH Logic Level L = LOW Logic Level *H = High Impedance Output State, Open Drain

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parame | Parameter | | Max | Unit |
|-------------------------------------|--------------------------------------|------------------------|------|------|------|
| V _{CC} | Supply Voltage | | -0.5 | 6.5 | V |
| V _{IN} | DC Input Voltage | | -0.5 | 6.5 | V |
| V _{OUT} | DC Output Voltage | | -0.5 | 6.5 | V |
| I _{IK} | DC Input Diode Current | V _{IN} < 0 V | = | -50 | mA |
| I _{OK} | DC Output Diode Current | V _{OUT} < 0 V | = | -50 | mA |
| I _{OUT} | DC Output Current | | = | ±50 | mA |
| I _{CC} or I _{GND} | DC V _{CC} or Ground Current | | = | ±50 | mA |
| T _{STG} | Storage Temperature Range | | -65 | +150 | °C |
| TJ | Junction Temperature Under Bias | | - | +150 | °C |
| TL | Junction Lead Temperature (Solde | ring, 10 Seconds) | = | +260 | °C |
| P_{D} | Power Dissipation in Still Air | SC-74A / SOT23-5 | = | 390 | mW |
| | | SC-88A | - | 332 | |
| | | MicroPak-6 | = | 812 | |
| | | MicroPak2™-6 | - | 812 | |
| ESD | Human Body Model, JEDEC: JESD22-A114 | | = | 4000 | V |
| | Charge Device Model, JEDEC: JE | SD22-C101 | = | 2000 | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------------------|-------------------------------|---------------------------------------|------|-----|------|
| V _{CC} | Supply Voltage Operating | | 1.65 | 5.5 | V |
| | Supply Voltage Data Retention | | 1.50 | 5.5 | |
| V _{IN} | Input Voltage | | 0 | 5.5 | V |
| V _{OUT} | Output Voltage | | 0 | 5.5 | V |
| T _A | Operating Temperature | | -40 | +85 | °C |
| t _r , t _f | Input Rise and Fall Times | V _{CC} = 1.8 V, 2.5 V ±0.2 V | 0 | 20 | ns/V |
| | | V _{CC} = 3.3 V ±0.3 V | 0 | 10 | |
| | | V _{CC} = 5.0 V ±0.5 V | 0 | 5 | |
| $\theta_{\sf JA}$ | Thermal Resistance | SC-74A / SOT23-5 | - | 320 | °C/W |
| | | SC-88A | - | 377 | |
| | | MicroPak-6 | - | 154 | |
| | | MicroPak2-6 | - | 154 | |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

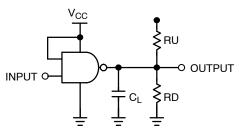
DC ELECTICAL CHARACTERISTICS

| | | | | T, | λ = +25° | ·C | T _A = -40 | to +85°C | |
|------------------|---------------------------|---------------------|---|----------------------|----------|----------------------|----------------------|----------------------|------|
| Symbol | Parameter | V _{CC} (V) | Conditions | Min | Тур | Max | Min | Max | Unit |
| V _{IH} | HIGH Level Input Voltage | 1.65 to 1.95 | | 0.65 V _{CC} | - | - | 0.65 V _{CC} | - | V |
| | | 2.30 to 5.50 | | 0.70 V _{CC} | - | - | 0.70 V _{CC} | - | |
| V _{IL} | LOW Level Input Voltage | 1.65 to 1.95 | | - | - | 0.35 V _{CC} | - | 0.35 V _{CC} | V |
| | | 2.30 to 5.50 | | - | - | 0.30 V _{CC} | - | 0.30 V _{CC} | |
| I _{LKG} | HIGH Level Output Leakage | 5.50 | $V_{IN} = V_{IL},$ $V_{OUT} = V_{CC}$ or GND | - | - | ±5 | - | ±10 | μΑ |
| V _{OL} | LOW Level Output Voltage | 1.65 | $V_{IN} = V_{IH} \text{ or } V_{IL},$ | - | 0.00 | 0.10 | - | 0.10 | V |
| | | 1.80 | I _{OL} = 100 μA | _ | 0.00 | 0.10 | - | 0.10 | |
| | | 2.30 | | _ | 0.00 | 0.10 | - | 0.10 | |
| | | 3.00 | | _ | 0.00 | 0.10 | - | 0.10 | |
| | | 4.50 | | - | 0.00 | 0.10 | - | 0.10 | 1 |
| | | 1.65 | I _{OL} = 4 mA | - | 0.80 | 0.24 | - | 0.24 | 1 |
| | | 2.30 | I _{OL} = 8 mA | - | 0.10 | 0.30 | - | 0.30 | |
| | | 3.00 | I _{OL} = 16 mA | - | 0.15 | 0.40 | - | 0.40 | |
| | | 3.00 | I _{OL} = 24 mA | - | 0.22 | 0.55 | - | 0.55 | |
| | | 4.50 | I _{OL} = 32 mA | - | 0.22 | 0.55 | - | 0.55 | |
| I _{IN} | Input Leakage Current | 5.50 | V _{IN} = 5.5 V, GND | - | - | ±1 | - | ±10 | μΑ |
| I _{OFF} | Power Off Leakage Current | 0 | V _{IN} or V _{OUT} = 5.5 V | - | - | 1 | - | 10 | μΑ |
| I _{CC} | Quiescent Supply Current | 5.50 | V _{IN} = 5.5 V, GND | - | - | 2 | _ | 20 | μΑ |

AC ELECTRICAL CHARACTERISTICS

| | | | | - | Γ _A = +25°C | | T _A = -40 | to +85°C | |
|------------------|---|---------------------|---|-----|------------------------|------|----------------------|----------|------|
| Symbol | Parameter | V _{CC} (V) | Conditions | Min | Тур | Max | Min | Max | Unit |
| t _{PZL} | Propagation Delay | 1.65 | C _L = 50 pF, | - | 6.5 | 12.7 | - | 13.2 | ns |
| | (Figure 4, 5) | 1.80 | RU = 500 Ω , RD = 500 Ω , | - | 5.4 | 10.5 | - | 11.0 | |
| | | 2.50 ±0.20 | $V_{IN} = 2 \cdot V_{CC}$ | - | 3.5 | 7.0 | - | 7.5 | |
| | | 3.30 ±0.30 | | - | 2.8 | 5.0 | - | 5.2 | |
| | | 5.00 ±0.50 | | - | 2.2 | 4.3 | - | 4.5 | |
| t _{PLZ} | | 1.65 | C _L = 50 pF, | - | 5.5 | 12.7 | - | 13.2 | ns |
| | | 1.80 | $R\overline{U} = 500 \Omega$, $RD = 500 \Omega$, | - | 4.6 | 10.5 | - | 11.0 | |
| | | 2.50 ±0.20 | $V_{IN} = 2 \cdot V_{CC}$ | - | 3.0 | 7.0 | - | 7.5 | |
| | | 3.30 ±0.30 | | - | 2.1 | 5.0 | - | 5.2 | |
| | | 5.00 ±0.50 | | - | 1.3 | 4.3 | - | 4.5 | |
| C _{IN} | Input Capacitance | 0.00 | | - | 4.0 | - | - | - | pF |
| C _{OUT} | Output Capacitance | 0.00 | | - | 5.0 | _ | - | - | pF |
| C _{PD} | C _{PD} Power Dissipation Capacitance | 3.30 | | - | 5.1 | - | - | - | pF |
| | (Note 2) (Figure 6) | 5.00 | | - | 7.3 | - | - | - | |

^{2.} C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).



NOTE:

3. CL includes load and stray capacitance. Input PRR = 10 MHz $t_{\rm W}$ = 500 ns.

Figure 4. AC Test Circuit

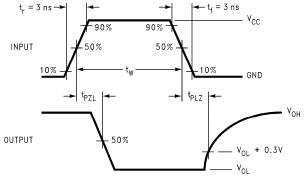
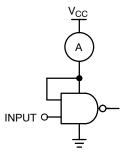


Figure 5. AC Waveforms



NOTE:

4. Input = AC Waveform; $t_r = t_f = 1.8$ ns; PRR = 10 MHz; Duty Cycle = 50%.

Figure 6. Test Circuit

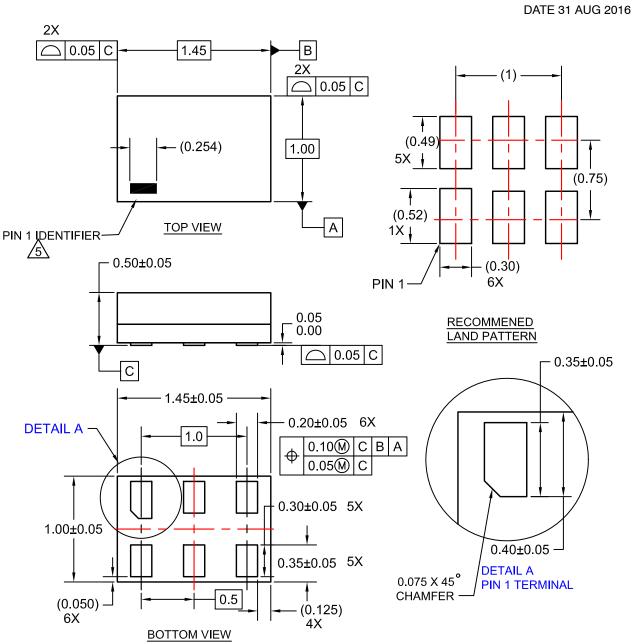
DEVICE ORDERING INFORMATION

| Device | Top Mark | Packages | Shipping [†] |
|-------------------|----------|------------------|-----------------------|
| NC7SZ38M5X | 7Z38 | SC-74A | 3000 / Tape & Reel |
| NC7SZ38M5X-L22090 | 7Z38 | SOT23-5 | 3000 / Tape & Reel |
| NC7SZ38P5X | Z38 | SC-88A | 3000 / Tape & Reel |
| NC7SZ38P5X-L22057 | Z38 | SC-88A | 3000 / Tape & Reel |
| NC7SZ38L6X | A6 | SIP6, MicroPak | 5000 / Tape & Reel |
| NC7SZ38L6X-L22175 | A6 | SIP6, MicroPak | 5000 / Tape & Reel |
| NC7SZ38FHX | A6 | UDFN6, MicroPak2 | 5000 / Tape & Reel |
| NC7SZ38FHX-L22175 | A6 | UDFN6, MicroPak2 | 5000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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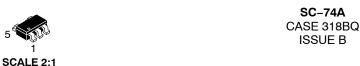
NOTES:

- 1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y14.5M-2009
- 4.PIN ONE IDENTIFIER IS 2X LENGTH OF ANY
 - OTHER LINE IN THE MARK CODE LAYOUT.

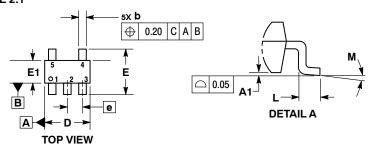
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| DESCRIPTION: | SIP6 1.45X1.0 | | PAGE 1 OF 1 |

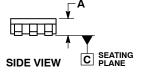
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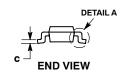




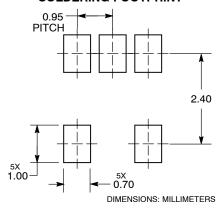
DATE 18 JAN 2018







RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

- IES:
 DIMENSIONING AND TOLERANCING PER ASME
 Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
 THICKNESS. MINIMUM LEAD THICKNESS IS THE
 MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

| | MILLIMETERS | | |
|-----|-------------|------|--|
| DIM | MIN | MAX | |
| Α | 0.90 | 1.10 | |
| A1 | 0.01 | 0.10 | |
| b | 0.25 | 0.50 | |
| С | 0.10 | 0.26 | |
| D | 2.85 | 3.15 | |
| E | 2.50 | 3.00 | |
| E1 | 1.35 | 1.65 | |
| е | 0.95 BSC | | |
| L | 0.20 | 0.60 | |
| М | 0 ° | 10° | |

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ", may or may not be present. Some products may not follow the Generic Marking.

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|------------------|-------------|--|-------------|
| DESCRIPTION: | SC-74A | | PAGE 1 OF 1 |

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SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

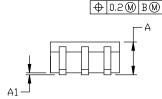
DATE 11 APR 2023

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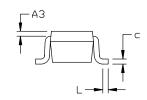
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- 2. CONTROLLING DIMENSION: MILLIMETERS
- 419A-01 DBSDLETE. NEW STANDARD 419A-02
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

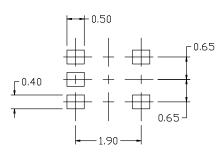
| DIM | MI | LLIMETE | RS |
|--------|----------|---------|------|
| الملتط | MIN. | N□M. | MAX. |
| А | 0.80 | 0.95 | 1.10 |
| A1 | | | 0.10 |
| A3 | 0.20 REF | | |
| b | 0.10 | 0.20 | 0.30 |
| С | 0.10 | | 0.25 |
| D | 1.80 | 2.00 | 2,20 |
| Е | 2.00 | 2.10 | 2.20 |
| E1 | 1.15 | 1.25 | 1.35 |
| е | 0.65 BSC | | |
| L | 0.10 | 0.15 | 0.30 |

е Ε1 0



5X b





RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

out in the datasheet refer to the device

XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

| STYLE 1 | • |
|---------|-----------|
| | EMITTER |
| | BASE |
| | COLLECTOR |
| 5. | COLLECTOR |

PIN 1. EMITTER 2

2. BASE 2

3. EMITTER 1

4. COLLECTOR

5. COLLECTOR 2/BASE 1

STYLE 6:

STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR CATHODE

2. EMITTER 3. BASE

4. COLLECTOR

5. COLLECTOR

STYLE 7:

PIN 1. BASE

STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1

PIN 1. CATHODE 2. COLLECTOR 3. N/C

4. BASE

STYLE 8:

STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3 SOURCE 1 4. GATE 1 5. GATE 2

3. ANODE 4. ANODE

STYLE 5: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4

STYLE 9: Note: Please refer to datasheet for PIN 1. ANODE 2. CATHODE style callout. If style type is not called

 ANODE
 ANODE datasheet pinout or pin assignment. 5. EMITTER Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

DOCUMENT NUMBER: 98ASB42984B **DESCRIPTION:** SC-88A (SC-70-5/SOT-353) PAGE 1 OF 1

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UDFN6 1.0X1.0, 0.35P CASE 517DP ISSUE O **DATE 31 AUG 2016** 0.89 0.05 C В 1.00±0.050 Α 2X 5X 0.40 PIN 1 MIN 250uM 0.66 1 00±0 050 1X 0.45 0.05 C **TOP VIEW** 6X 0.19 2X RECOMMENDED LAND PATTERN FOR SPACE CONSTRAINED PCB 0.05 C - 0.90 -0.50±0.05 5X 0.52 SIDE VIEW 6X 0.14±0.05 (0.08)4X -0.73 **DETAIL A** 3 1X 0.57 - 0.20 6X ALTERNATIVE LAND PATTERN FOR UNIVERSAL APPLICATION (0.05)6X5X 0.30±0.05 0.60 0.10M|C|B|A(80.0).05 C 4X 0.35±0.050 **BOTTOM VIEW** NOTES: A. COMPLIES TO JEDEC MO-252 STANDARD B. DIMENSIONS ARE IN MILLIMETERS. C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009

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|------------------|----------------------|---|-------------|--|
| DESCRIPTION: | UDFN6 1.0X1.0, 0.35P | | PAGE 1 OF 1 | |

0.075X45°

CHAMFER

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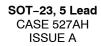
DETAIL A

PIN 1 LEAD SCALE: 2X





REFERENCE



DATE 09 JUN 2021

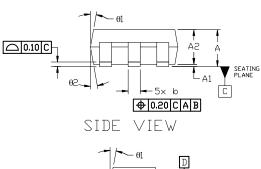
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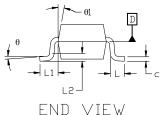
F1 F

В

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS.
 MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS, MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED O. 25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- 5. DIMENSION '6' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE '6' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.



TOP VIEW



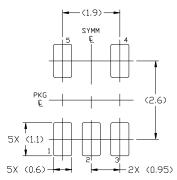
GENERIC MARKING DIAGRAM*



XXX = Specific Device Code M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

| | MILLIMETERS | | | |
|-----|-------------|------|------|--|
| DIM | MIN. | N□M. | MAX. | |
| Α | 0.90 | _ | 1.45 | |
| A1 | 0.00 | _ | 0.15 | |
| A2 | 0.90 | 1.15 | 1.30 | |
| b | 0.30 | _ | 0.50 | |
| С | 0.08 | _ | 0.22 | |
| D | 2.90 BSC | | | |
| Ε | 2.80 B2C | | | |
| E1 | 1.60 BSC | | | |
| е | 0.95 BSC | | | |
| L | 0.30 | 0.45 | 0.60 | |
| L1 | 0.60 REF | | | |
| L2 | 0.25 REF | | | |
| θ | 0° | 4° | 8* | |
| θ1 | 0° | 10° | 15° | |
| θ2 | 0* | 10° | 15° | |



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

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